Contents

Preface v

Acknowledgment vi

Committees vi

Preparation of diamond films — 1

Low temperature growth of highly purified diamond films using microwave plasma-assisted chemical vapour deposition 1
Y. Muranaka, H. Yamashita and H. Miyadera (Ibaraki, Japan)

Growth and properties of diamond films prepared by microwave plasma chemical vapour deposition using different oxygen-containing source gases 13
L. Schäfer and C.-P. Klages (Hamburg, F.R.G.)

Substrate-free gas-phase synthesis of diamond powder by CO_2 laser pyrolysis of C_2H_4 22
P. R. Buerki and S. Leutwyler (Berne, Switzerland)

Investigation of diamond growth in a new planar microwave plasma source 29
A. Ohl and M. Schmidt (Greifswald, F.R.G.)

Thermal chemical vapour deposition of homoepitaxial diamond: dependence of surface morphology and defect structure on substrate orientation 39
W. J. P. van Enckevort (Cuijk, The Netherlands), G. Janssen, W. Vollenberg, M. Chermin, L. J. Giling (Nijmegen, The Netherlands) and M. Seal (Amsterdam, The Netherlands)

Clarification of the effect of bias in the hot filament process 51
W. Banholzer and R. Kehl (Schenectady, NY, U.S.A.)

Aspects of diamond deposition by anomalous pulsed d.c. glow-discharge-activated chemical vapor deposition 59
D. Satrapa, R. Haubner and B. Lux (Vienna, Austria)

Preparation of diamond-like films — 1

Deposition of carbon films by the dissociation of methane in r.f. discharge 69
W. Zhang and Y. Catherine (Nantes, France)

Deposition of a diamond-like carbon film on a stainless steel substrate: studies of intermediate layers 84
N. Yoshino, Y. Shibuya, K. Naoi and T. Nanya (Saitama, Japan)

Plasma deposition of hydrogenated amorphous carbon (a-C:H) under a wide bias potential range 89
C. Serra, E. Pascual, F. Maass and J. Esteve (Barcelona, Spain)

Properties of diamond-like coatings prepared by vacuum arc deposition 98
I. I. Aksenov and V. E. Strel'nitskij (Kharkov, U.S.S.R.)

The system for depositing hard diamond-like films onto complex-shaped machine elements in an r.f. arc plasma 106
S. Mitura, Z. Haś and V. Gorokhovsky (Łódź, Poland)

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Preparation of diamond films — 2

Rapid growth of single-crystal diamond on diamond substrates 113
G. Janssen, W. Vollenberg, L. J. Giling (Nijmegen, The Netherlands), W. J. P. van Enckevort, J. J. D. Schaminée (Cuijk, The Netherlands) and M. Seal (Amsterdam, The Netherlands)

Nickel-assisted metastable diamond formation (surface recrystallization) in a dissolution medium at atmospheric pressure 127
K. A. Cherian (Gujarat, India)

Diamond layers deposited from impulse plasma 144
A. Sokołowska, A. Olszyna, A. Michalski and K. Zdunek (Narbutta, Poland)

The reaction of atomic hydrogen with a-C:H and diamond films 156
E. Vietzke, V. Philipps, K. Flaskamp (Jülich, F.R.G.), P. Koidl and Ch. Wild (Freiburg, F.R.G.)

Preparation of diamond-like films — 2

Investigation of hard a-C:H layers generated by a novel r.f. plasma beam source 162
H. Oechsner and B. Tomcik (Kaiserslautern, F.R.G.)

A new "cyclic" r.f. plasma method for the deposition of diamond-like carbon films 173
X.-D. Pan and D. J. Fabrian (Glasgow, U.K.)

Diamond-like carbon coatings by arc-discharge methods. 180
J. Koskinen, A. Anttila (Helsinki, Finland) and J.-P. Hirvonen (Los Alamos, NM, U.S.A.)

Deposition of diamond-like carbon films by low energy ion beam and d.c. magnetron sputtering 188
A. Singh and P. Lavigne (Ste-Foy, Que., Canada)

Poster session 1 on diamond-like films

Wear resistance of diamond-like coatings. 201
S. D. Gorpinchenko, S. M. Klotsman, E. V. Kuzmina, S. A. Plotnikov and I. Sh. Trachtenberg (Sverdlovsk, U.S.S.R.)

The use of deuterium for examination of C:H films. 209
S. M. Klotsman, S. A. Plotnikov, A. P. Rubshtein, I. Sh. Trakhtenberg and V. B. Vykhodets (Sverdlovsk, U.S.S.R.)

Diamond-like properties of amorphous carbon and hydrogenated amorphous carbon thin films. 218
F. Demichelis, A. Tagliaferro (Turin, Italy) and D. Das Gupta (Siliguri, India)

Hydrogenation of the atomic carbon deposited on the Pt(111) surface studied by the energy electron loss spectroscopy and thermal desorption mass spectrometry 224
M. Yu. Smirnov, A. R. Cholach, V. V. Gorodetskii (Novosibirsk, U.S.S.R.), N. R. Gall, A. Ya. Tontegode and E. V. Rut'kov (Leningrad, U.S.S.R.)

Properties and structure of carbon films prepared by ion-beam deposition 233
M. Okada, T. Kono, K. Tanaka, M. Sato and K.-I. Fujimoto (Kawasaki, Japan)

Preparation and study of laser plasma diamond 244
C. B. Collins, F. Davanloo, E. M. Juengerman, D. R. Jander and T. J. Lee (Richardson, TX, U.S.A.)

Wear resistance of diamond-like carbon coatings. 252
I. I. Aksenov and V. E. Strel'nitskij (Kharkov, U.S.S.R.)

Deposition of diamond-like carbon film by laser ion source 257
S. S. Wagal (Poona, India)

Ellipsometric study of diamond-like thin films. 263
E. Pascual, C. Serra, J. Esteve and E. Bertran (Barcelona, Spain)

Light-induced variations of optical properties of diamond-like films 269
V. P. Ageev, N. I. Chapliev, T. N. Glushko, T. V. Kononenko, A. V. Kuzmichov, A. A. Smolin, V. E. Strelnitsky, V. F. Dorfman and B. N. Pypkin (Moscow, U.S.S.R.)

Ar^+ laser annealing and etching of hydrogenated amorphous carbon films 279
V. Yu. Armeyev, N. I. Chapliev, E. N. Loubnin, V. I. Mikhailov, V. G. Ralchenko and V. E. Strelnitsky (Moscow, U.S.S.R.)

Study of the sp^2-to-sp^3 ratio of dual-ion-beam sputtered hydrogenated amorphous carbon films. 287
S. Scaglione, R. Giorgi, J. C. Lascovich (Rome, Italy) and G. Ottaviani (Modena, Italy)

Structure and properties of carbon films prepared by pulsed vacuum arc deposition 292
E. I. Tochitsky, A. V. Stanishevskii, I. A. Kapustin, V. V. Akulich and O. V. Selifanov (Minsk, U.S.S.R.)

Physical properties of plasma-enhanced chemically vapour deposited hydrogenated and nitrogenated amorphous carbons. 299
M. Ricci, M. Trinquecoste and P. Delhaes (Pessac, France)

Application of "diamond polymer" films in hard disk technology. 308
D. Latev (Sofia, Bulgaria), V. Dorfman and B. Pypkin (Moscow, U.S.S.R.)

Physical properties of carbon films produced using a hybrid physical vapour deposition technique. 315
P. Holiday, A. Dehbi-Alaoui and A. Matthews (Hull, U.K.)

Optical properties of carbon films deposited using a hybrid physical vapour deposition technique. 327
A. Dehbi-Alaoui, P. Holiday and A. Matthews (Hull, U.K.)

Characterization of diamond films

The 1.681 eV centre in polycrystalline diamond 336
C. D. Clark and C. B. Dickerson (Reading, U.K.)

Electrical properties of doped and undoped chemically vapour deposited diamond films 344
R. E. Harper, C. Johnston, N. G. Blamires, P. R. Chalker and I. M. Buckley-Golder (Didcot, U.K.)

Photoconductive measurements on microwave-assisted plasma-enhanced chemically vapor deposited diamond films 356
L. S. Pan, D. R. Kania, P. Pianetta, M. Landstrass, O. L. Landen and L. S. Plano (Stanford, CA, U.S.A.)

Evaluation of internal stresses present in chemical vapor deposition diamond films 365
P. R. Chalker, A. M. Jones, C. Johnston and I. M. Buckley-Golder (Didcot, U.K.)

The effects of methane concentration in hydrogen on the microstructure and properties of diamond films grown by hot-filament chemical vapour deposition 375
C. V. Cooper (East Hartford, CT, U.S.A.) and C. P. Beetz, Jr., (New Milford, CT, U.S.A.)

Thermal conductivity and structure of diamond films 388
V. I. Nepsha, V. R. Grinberg, Yu. A. Klyuev, N. A. Kolchemanov and A. M. Naletov (Moscow, U.S.S.R.)

High temperature electrical conductivity measurements of natural diamond and diamond films 392
J. W. Vandersande and L. D. Zoltan (Pasadena, CA, U.S.A.)

Preparation of diamond-like films — 3

Carbon deposition using an expanding cascaded arc d.c. plasma 401
J. J. Beulens, A. J. M. Buuron and D. C. Schram (Eindhoven, The Netherlands)

The properties of amorphous carbon films obtained by ion-beam-assisted carbon evaporation 418
A. Schröer, W. Ensinger, G. Frech and G. K. Wolf (Heidelberg, F.R.G.)

Direct ion-beam deposition of amorphous hydrogenated carbon films 426
R. Locher, C. Wild and P. Koidl (Freiburg, F.R.G.)

Determination of the optimal energy range for obtaining diamond-like films by ion implantation 433
J. C. Pivin, M. Allouard (Orsay, France) and G. Rotureau (Arcueil, France)

Ion beam deposition of diamond-like carbon films 445
V. M. Puzikov and A. V. Semenov (Kuarkov, U.S.S.R.)

Laser arc: a new method for preparation of diamond-like carbon films 455
H.-J. Scheibe, P. Siemroth, W. Pompe and B. Schoeneich (Dresden, F.R.G.)

Applications of diamond films

Microfabrication of diamond films: selective deposition and etching 465
S. Miyauchi, K. Kumagai, K. Miyata, K. Nishimura, K. Kobashi, A. Nakaue (Kobe, Japan), J. T. Glass (Raleigh, NC, U.S.A.) and I. M. Buckley-Golder (Didcot, U.K.)

Planing of synthetic diamond film by the Penning discharge microsputtering method 474
H. Funamoto and O. Koseki (Chiba, Japan) and T. Sugita (Tokyo, Japan)

Photoelectron emission from diamond films 481
L. L. Bouilov, N. I. Chapliev, V. B. Kvaskov, V. I. Konov, S. M. Pimenov, B. V. Spytsin, I. G. Teremetskaya and A. Yu. Zlobin (Moscow, U.S.S.R.)

Diamond–nickel interfaces: calculation of the electronic and atomic structure and Schottky barriers 487
S. C. Erwin and W. E. Pickett (Washington, DC, U.S.A.)

Dielectric strength of thin passivating diamond films for semiconductor devices 496
J. Szmidt, T. Brozek, R. H. Gantz and A. Olszyna (Warsaw, Poland)

Preparation of diamond-like films — 4

Carbon films deposited from UV laser plasma 503
A. A. Gorbunov and V. I. Konov (Moscow, U.S.S.R.)

Characterization of diamond-like films prepared by laser ablation of graphite . . . 509
E. B. D. Bourdon, W. W. Duley, A. P. Jones and R. H. Prince (Toronto, Ont., Canada)

Theoretical thermochemistry of diamond-like carbon film growth 517
P. Deák, J. Giber (Budapest, Hungary) and H. Oechsner (Kaiserslautern, F.R.G.)

Electrical erosion pulsed plasma accelerators for preparing diamond-like coatings 522
E. I. Tochitsky, O. V. Selifanov, V. V. Akulich, I. A. Kapustin and A. V. Stanishevskii (Minsk, U.S.S.R.)

Poster session 2 on diamond films

A laser-induced chemical transport reaction method for diamond deposition 528
K. Fabisiak, P. Hoffman, J.-M. Philippoz and H. van den Bergh (Lausanne, Switzerland)

Formation of diamond-like carbon films by 50 Hz sputtering from dual graphite targets. 533
V. Amornkitbamrung and N. Suttisiri (Kaen, Thailand)

Electron spin resonance study of the defects in polycrystalline diamond films 538
T. A. Karpukhina, L. L. Bouilov and V. F. Chuvaev (Moscow, U.S.S.R.)

Shape changes during growth of diamond particles and films synthesized from CH_4–H_2–(O_2) by tungsten-filament chemical vapour deposition 545
Y.-J. Balk and K. Y. Eun (Seoul, Korea)

Diamond: a novel substrate for thick film technology. 553
H. Lux and W. Smetana (Vienna, Austria)

Depth distributions and range parameters for elements implanted into single-crystal diamonds and chemically vapor-deposited polycrystal diamond films 559
R. G. Wilson (Malibu, CA, U.S.A.)

Evaluation of abrasion resistance and adhesion strength of brazed diamond film by a shearing test. 572
M. Murakawa and S. Takeuchi (Saitama, Japan)

Atomic cluster study of chemisorption and epitaxial diamond films on an Si(100) substrate 578
W. S. Verwoerd and K. Weimer (Pretoria, South Africa)

Carburization of tungsten and tantalum filaments during low-pressure diamond deposition 585
S. Okoli, R. Haubner and B. Lux (Vienna, Austria)

Chemical vapour deposition diamond coatings on cemented carbide tools 600
J. Oakes (Nashville, TN, U.S.A.), X. X. Pan, R. Haubner and B. Lux (Vienna, Austria)

Relationship between emission spectroscopy and structural properties of diamond films synthesized by plasma-assisted chemical vapor deposition. 608
B. Marcus, M. Mermoux, F. Vinet, A. Campargue and M. Chenevier (St.-Martin d'Hères, France)

Electron spin resonance spectroscopy of impure and pure structural defects in the diamond 618
N. D. Samsonenko, V. V. Tokiy, S. V. Gorban and V. I. Timchenko (Makeyeuka, U.S.S.R.)

Plasma-assisted chemical vapour deposition of diamond from an ethanol–water–hydrogen gas mixture. 623
L. Kostadinov and D. Dobrev (Sofia, Bulgaria)

X-ray emission spectra of diamond films 628
E. Z. Kurmaev and S. N. Shamin (Sverdlovsk, U.S.S.R.)

Friction of diamond on diamond and chemical vapour deposition 631
Z. Feng and J. E. Field (Cambridge, U.K.)

Applications of diamond and diamond-like films

Improvements in adhesive strength and cutting performance of diamond-coated tools 646
K. Saijo, M. Yagi, S. Shibuki and S. Takatsu (Kawasaki, Japan)

Application of brazed diamond film as insert for turning aluminium alloys 654
M. Murakawa and S. Takeuchi (Saitama-Prefecture, Japan)

Diamond-like carbon applied to bioengineering materials 662
A. C. Evans, J. Franks and R. J. Revell (Teddington, U.K.)

Characterization of diamond-like films

The structure of a C:H by neutron and X-ray scattering. 668
R. J. Newport, P. J. R. Honeybone, S. P. Cottrell (Canterbury, U.K.), J. Franks, P. Revell (Teddington, U.K.), R. J. Cernik (Warrington, U.K.) and W. S. Howells (Didcot, U.K.)

Elastic characterization of diamond films by acoustic microscopy 677
R. D. Weglein and A. K. Mal (Los Angeles, CA, U.S.A.)

Brillouin light scattering from the Rayleigh surface phonon of thermally annealed a-C:H films 687
X. Jiang, P. Grünberg, K. Reichelt and B. Stritzker (Jülich, F.R.G.)

The properties of titanium-containing amorphous hydrogenated carbon films. . . . 691
M. Wang, K. Schmidt, K. Reichelt (Jülich, F.R.G.), H. Dimigen and H. Hübsch (Hamburg, F.R.G.)

Microindentation fatigue tests on submicron carbon films. 696
T. W. Wu, A. L. Shull (San Jose, CA, U.S.A.) and R. Berriche (Minneapolis, MN, U.S.A.)

Tribological properties and characterization of diamond-like carbon coatings with silicon prepared by plasma-assisted chemical vapour deposition 710
K. Oguri and T. Arai (Aichi, Japan)

The optical and mechanical properties of carbon films grown using a fast atom beam source 722
A. Dehbi-Alaoui and A. Matthews (Hull, U.K.) and J. Franks (Teddington, U.K.)

Optical and electronic applications of diamond-like films

Pulsed CO_2 laser damage of diamond-like carbon films 730
N. I. Chapliev, T. V. Kononenko, A. A. Smolin and V. E. Strelnitsky (Moscow, U.S.S.R.)

The origin of optical absorption and the electron spin resonance signal in amorphous carbon and amorphous hydrogenated carbon: a proposed density-of-states model 740
F. Demichelis, C. F. Pirri, A. Tagliaferro (Torino, Italy) and D. Dasgupta (Siliguri, India)

Diamond-like films as a protecting insulator for gas-detecting suspended-gate field effect transistors 746
H. Lorenz, J. Lechner and I. Eisele (Neubiberg, F.R.G.)

Textured structure of diamond-like carbon prepared with hydrogen 754
C. B. Collins, F. Davanloo, E. M. Juengerman, D. R. Jander and T. J. Lee (Richardson, TX, U.S.A.)

Mechanical applications of diamond-like films

Abrasion resistance of diamond-like carbon coatings on thick film resistor material 761
H.-J. Krokoszenski (Heidelberg, F.R.G.)

Superhard i-C coating used in complex processes of surface strengthening of tools and machine parts 770
N. Novikov, V. Gorokhovsky and B. Uryukov (Kiev, U.S.S.R.)

The formation of diamond-like carbon coatings for raising the wear resistance of precision friction pairs 792
E. I. Tochitsky, A. V. Stanishevskii, V. V. Akulich, O. V. Selifanov and I. A. Kapustin (Minsk, U.S.S.R.)